

# **Trench MOS Barrier Schottky Rectifier**

Reverse Voltage - 100 V

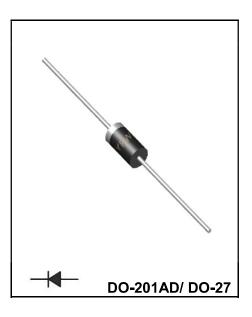
Forward Current - 5 A

# **FEATURES**

Advanced trench technology
Low forward voltage drop
Low power losses
High efficiency operation
Lead free in comply with EU RoHS 2011/65/EU directives

# **MECHANICAL DATA**

Case: DO-201AD/DO-27
Terminals: Solderable per MIL-STD-750, Method 2026
Approx. Weight: 0.98g / 0.0345oz



# Maximum Ratings (Per Leg) at Ta=25°C unless otherwise specified

Parameter		Symbols	Value	Units		
Maximum Repetitive Peak Reverse Voltage		VRRM	100	v		
Maximum RMS voltage		Vrms	100	v		
Maximum DC Blocking Voltage		VDC	100	v		
Maximum Average Forward Rectified Current	Per diode	F(AV)	5	A		
Peak Forward Surge Current, 8.3ms Single Half Sine-wave superimposed on rated load per diode		FSM	200	A		
Operating Temperature Range		TJ	-55 ~ +150	°C		
Storage Temperature Range		Тѕтс	-55 ~ +150	°C		
Typical Thermal Resistance Per diode(munted o FR-4 PCB)	n DO-27	Rejc	22	°C/W		

Note1: Thermal resistance from Junction to case per leg mounted on heatsink.

# Electrical Characteristics (Per Leg) unless otherwise specified

Characteristics		Symbols	Va	Units		
Forward Voltage Drop(Note2)			Тур	Мах		
at I <sub>F</sub> =2A Instantaneous forward voltage per diode	TA=25°C	VF	0.49	-	v	
	TA=125°C		0.36	-		
at I <sub>F</sub> =5A Instantaneous forward voltage per diode	TA=25°C		-	0.54		
	TA=125°C		0.48	-		
Instantaneous reverse current per diode at rated reverse voltage	TA=25°C	IR -	-	60	uA	
	TA=125°C		-	40	mA	

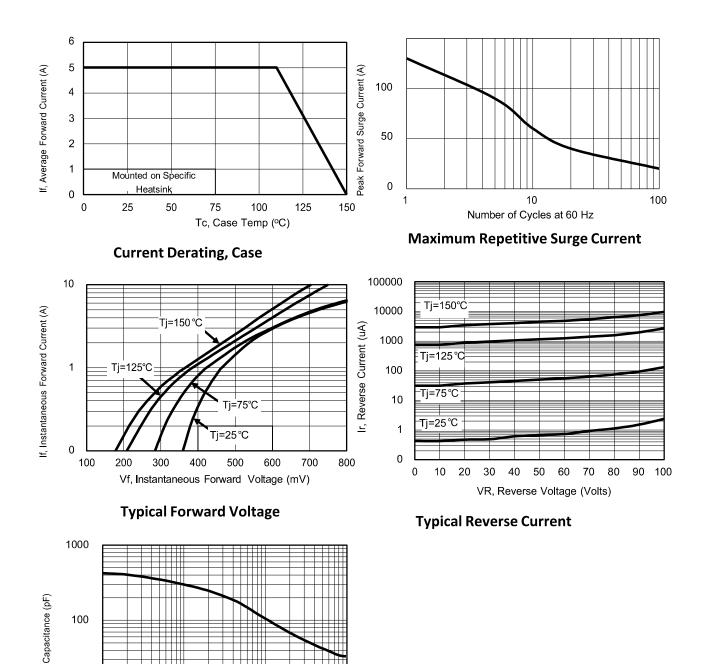
Note2: (1)Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq$  40 ms



# YFW5V100 DO-27

#### **Ratings and Characteristic Curves**



10

0

1

**Typical Junction Capacitance** 

10

Reverse Voltage (V)

100



# **Ordering information**

Package	Packing Description Packing Quantity		
DO-201AD/DO-27 -	bulk	250PCS/500PCS/Box 25000PCS/Carton	
	braid	1000PCS/1250PCS/Box 10000PCS/Carton/12500PCS/Carton	

# Package Dimensions

#### DO-201AD/DO-27

Φ	Dim.	Millimeter(mm)		INCHES	
- Model name - logo Mark		Min.	Max.	Min.	Max.
	A	-	9.50	-	0.370
	В	-	6.40	-	0.250
	С	1.20	1.30	0.048	0.052
	D	25.4	-	1.00	-





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